



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Package	I _D T _C = +25°C	
650V	$1.3\Omega @ V_{GS} = 10V$	ITO-220AB	9.0A	

Description

This new generation complementary dual MOSFET features low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

Applications

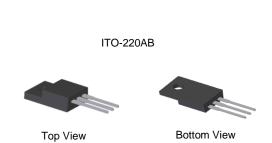
- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

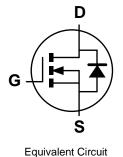
Features

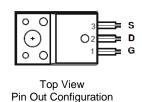
- Low Input Capacitance
- High BVDss Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: ITO-220AB
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: ITO-220AB 1.85 grams (Approximate)







Ordering Information (Note 4)

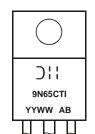
Part Number	Case	Packaging	
DMG9N65CTI	ITO-220AB	50 pieces/tube	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information

ITO-220AB



9N65CTI = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 13 = 2013) WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic				Value	Unit
Drain-Source Voltage			V_{DSS}	650	V
Gate-Source Voltage			V_{GSS}	±30	V
Continuous Drain Current (Notes 5 & 6) V _{GS} = 10V	Steady State	$T_C = +25$ °C $T_C = +70$ °C	I _D	9.0 7.0	А
Pulsed Drain Current (Note 7) 10µs pulse, pulse duty cycle<=1%				30	Α
Avalanche Current (Note 8) V _{DD} = 100V, V _{GS} = 10V, L = 60mH				2.7	A
Repetitive avalanche energy (Note 8) V _{DD} = 100V, V _{GS} = 10V, L = 60mH				260	mJ

Thermal Characteristics

Characteristic			Max	Unit
Power Dissipation (Note 5)	$T_C = +25$ °C $T_C = +70$ °C	P_{D}	13 8	W
Thermal Resistance, Junction to Case (Note 5) T _C = +25°C		R ₀ JC	8.84	°C/W
Operating and Storage Temperature Range			-55 to +150	°C

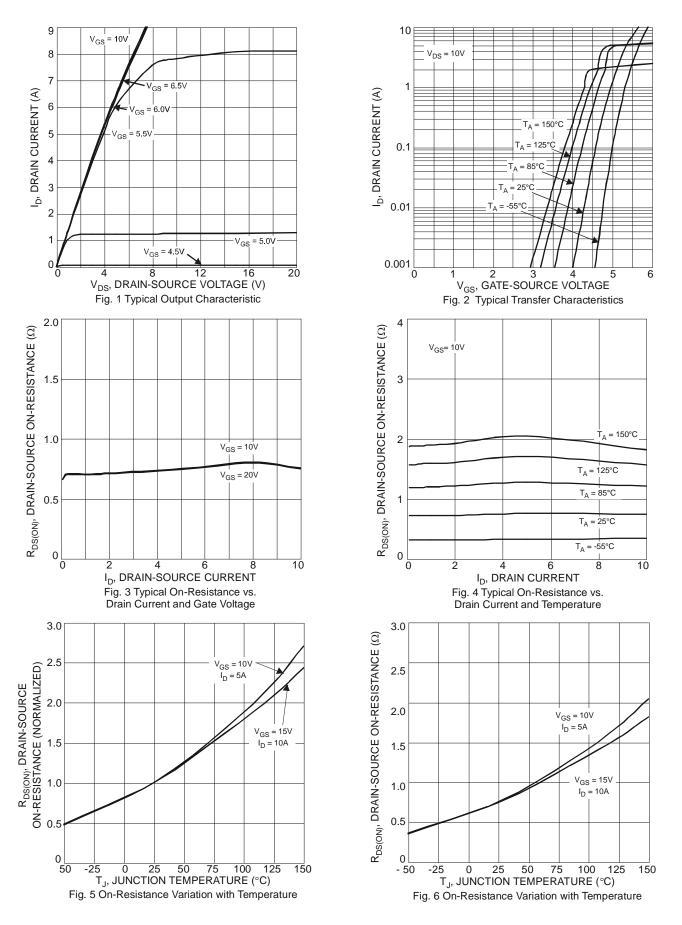
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	650	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}		-	1.0	μΑ	$V_{DS} = 650V, V_{GS} = 0V$	
Gate-Source Leakage	I_{GSS}	-	-	±100	nΑ	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(th)}	3	-	5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS (ON)}		0.7	1.3	Ω	$V_{GS} = 10V, I_D = 4.5A$	
Forward Transfer Admittance	Y _{fs}	•	8.5	-	S	$V_{DS} = 40V, I_{D} = 4.5A$	
Diode Forward Voltage	V_{SD}	-	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	ı	2310	-	pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	Coss		122	-			
Reverse Transfer Capacitance	C _{rss}	-	2.2	-			
Gate Resistance	R_g	-	2.2	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge V _{GS} = 10V	Qg	-	39	-		101/1/ 5001/	
Gate-Source Charge	Q_{gs}	-	8.5	-	nC	$V_{GS} = 10V, V_{DS} = 520V,$ $I_{D} = 8A$	
Gate-Drain Charge	Q_{gd}		11.9	-		ID = OA	
Turn-On Delay Time	t _{D(on)}	-	39	-	ns		
Turn-On Rise Time	t _r	-	29	-	ns	$V_{GS} = 10V, V_{DS} = 325V,$	
Turn-Off Delay Time	t _{D(off)}	-	122	-	ns	$R_G = 25\Omega$, $I_D = 8A$	
Turn-Off Fall Time	t _f	=	28	-	ns]	
Body Diode Reverse Recovery Time	t _{rr}		570	-	ns	$dI/dt = 100A/\mu s$, $V_{DS} = 100V$,	
Body Diode Reverse Recovery Charge	Q _{rr}	-	4.17	-	μC	I _F = 8A	

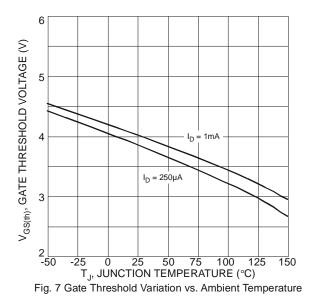
Notes:

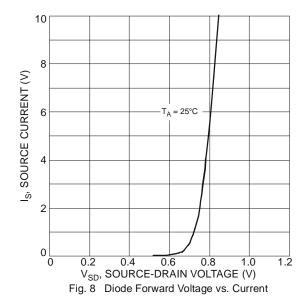
- 5. Device mounted on an infinite heatsink.
- Drain current limited by maximum junction temperature.
 Repetitive rating, pulse width limited by junction temperature.
- 8. I_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep $T_J = +25$ °C.
- 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to production testing.





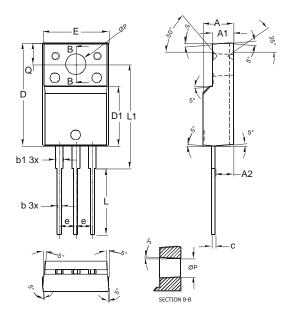






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



ITO-220AB						
Dim	Min	Тур	Max			
Α	4.50	4.70	4.90			
A1	3.04	3.24	3.44			
A2	2.56	2.76	2.96			
b	0.50	0.60	0.75			
b1	1.10	1.20	1.35			
C	0.50	0.60	0.70			
D	15.67	15.87	16.07			
D1	8.99	9.19	9.39			
е	2.54					
Е	9.91	10.11	10.31			
L	9.45	9.75	10.05			
L1	15.80	16.00	16.20			
Р	2.98	3.18	3.38			
ø	3.10	3.30	3.50			
All Dimensions in mm						



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